

P-Channel Enhancement Mode Power MOSFET

<p>Description</p> <p>The G2305 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge. It can be used in a wide variety of applications.</p> <p>General Features</p> <ul style="list-style-type: none"> ● V_{DS} -20V ● I_D (at $V_{GS} = -10V$) -4.8A ● $R_{DS(ON)}$ (at $V_{GS} = -4.5V$) < 46mΩ ● $R_{DS(ON)}$ (at $V_{GS} = -2.5V$) < 69mΩ ● 100% Avalanche Tested ● RoHS Compliant <p>Application</p> <ul style="list-style-type: none"> ● Power switch ● DC/DC converters 	<p>Schematic diagram</p> <p>pin Assignment</p> <p>SOT-23</p>
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Ordering Information			
Device	Package	Marking	Packaging
G2305	SOT-23	G2305	3000pcs/Reel

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, unless otherwise noted			
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Continuous Drain Current	I_D	-4.8	A
Pulsed Drain Current (note1)	I_{DM}	-15	A
Gate-Source Voltage	V_{GS}	± 10	V
Power Dissipation	P_D	1.7	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 To 150	°C

Thermal Resistance			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	R_{thJA}	74	°C/W

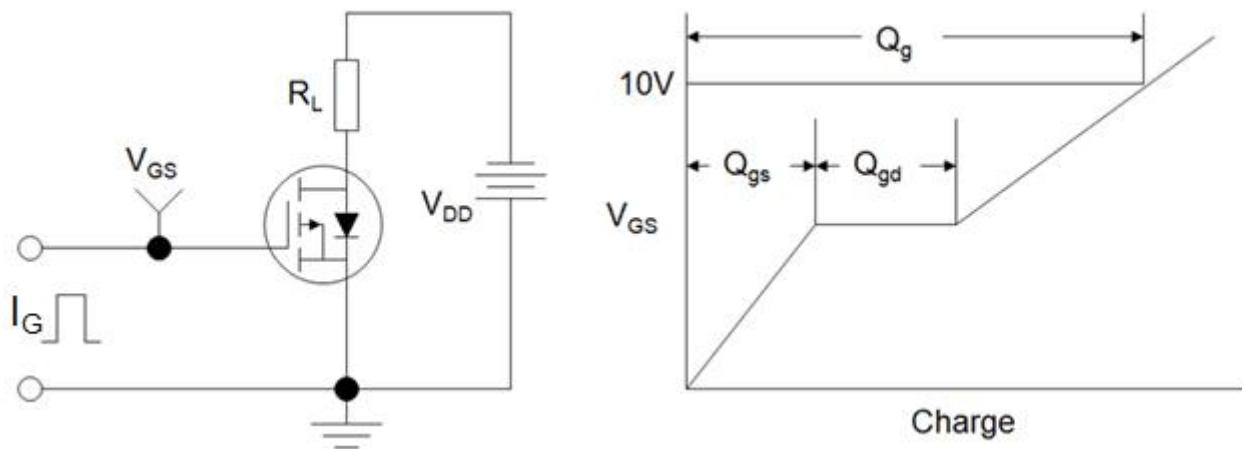
Specifications $T_J = 25^\circ\text{C}$, unless otherwise noted

Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static Parameters						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-20	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = -20\text{V}, V_{\text{GS}} = 0\text{V}$	--	--	-1	μA
Gate-Source Leakage	I_{GSS}	$V_{\text{GS}} = \pm 10\text{V}$	--	--	± 100	nA
Gate-Source Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$	-0.5	-0.7	-0.9	V
Drain-Source On-Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, I_D = -3\text{A}$	--	30	46	$\text{m}\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_D = -3\text{A}$	--	37	69	
Forward Transconductance	g_{FS}	$V_{\text{DS}} = -5\text{V}, I_D = -3\text{A}$	--	11	--	S
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = -10\text{V}, f = 1.0\text{MHz}$	--	759	--	pF
Output Capacitance	C_{oss}		--	112	--	
Reverse Transfer Capacitance	C_{rss}		--	98	--	
Total Gate Charge	Q_g	$V_{\text{DD}} = -10\text{V}, I_D = -3\text{A}, V_{\text{GS}} = -4.5\text{V}$	--	11	--	nC
Gate-Source Charge	Q_{gs}		--	2.2	--	
Gate-Drain Charge	Q_{gd}		--	2.6	--	
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -10\text{V}, I_D = -3\text{A}, R_G = 3\Omega$	--	36	--	ns
Turn-on Rise Time	t_r		--	8	--	
Turn-off Delay Time	$t_{\text{d}(\text{off})}$		--	76	--	
Turn-off Fall Time	t_f		--	56	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	$T_C = 25^\circ\text{C}$	--	--	-4.8	A
Body Diode Voltage	V_{SD}	$T_J = 25^\circ\text{C}, I_{\text{SD}} = -3\text{A}, V_{\text{GS}} = 0\text{V}$	--	--	-1.2	V
Reverse Recovery Charge	Q_{rr}	$I_F = -3\text{A}, V_{\text{GS}} = 0\text{V}$ $dI/dt = -100\text{A}/\mu\text{s}$	--	4.4	--	nC
Reverse Recovery Time	T_{rr}		--	24.8	--	ns

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. Identical low side and high side switch with identical R_G

Gate Charge Test Circuit



Switch Time Test Circuit



EAS Test Circuit



Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 1. Output Characteristics

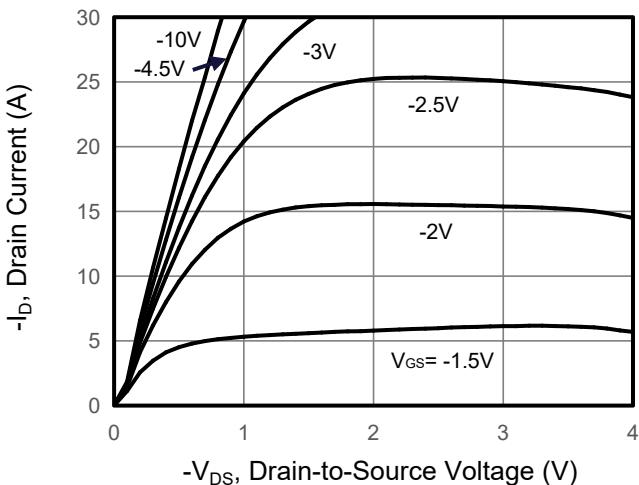


Figure 2. Transfer Characteristics

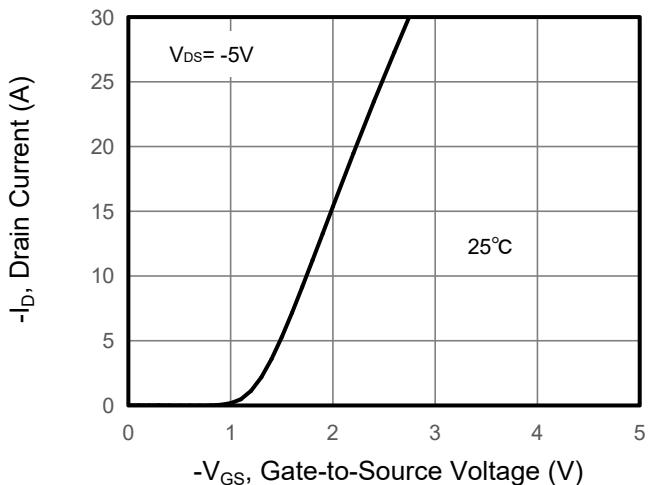


Figure 3. Drain Source On Resistance

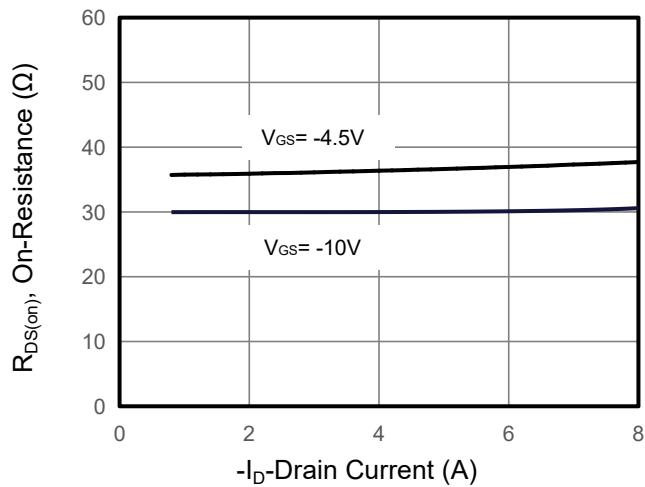


Figure 4. Gate Charge

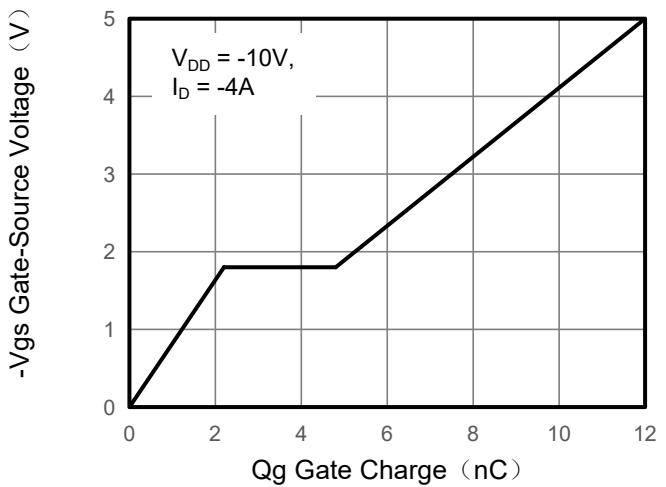


Figure 5. Capacitance

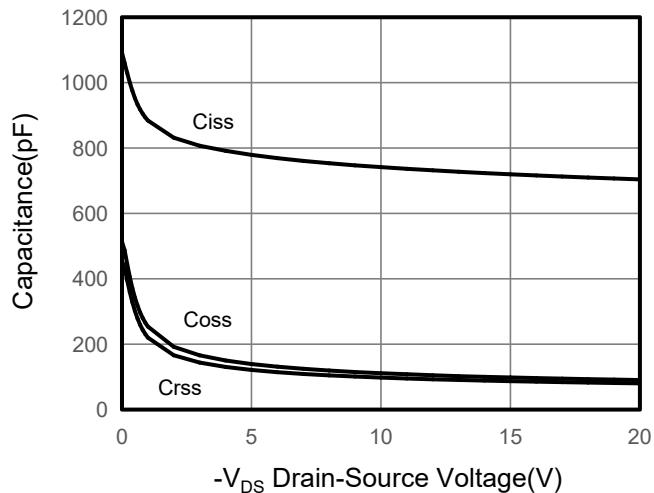
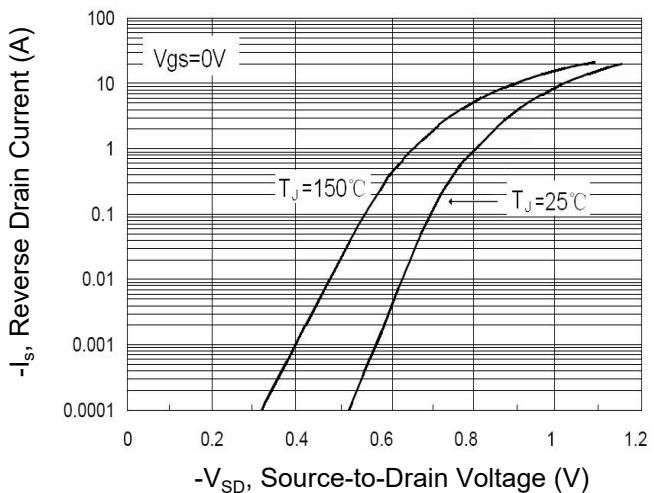


Figure 6. Source-Drain Diode Forward



Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 7. Drain-Source On-Resistance

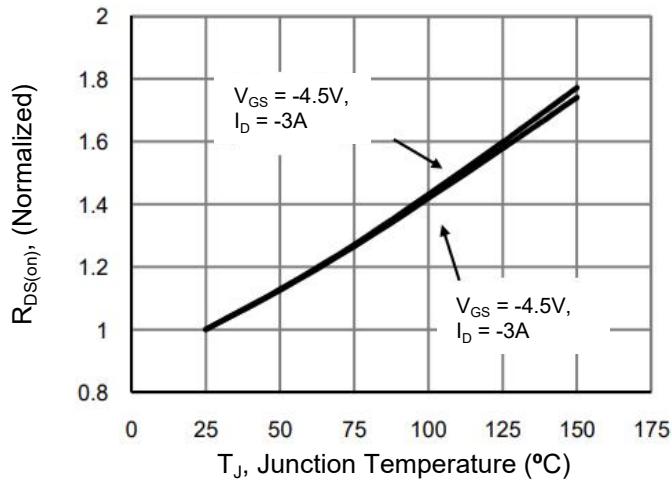


Figure 10. Safe Operation Area

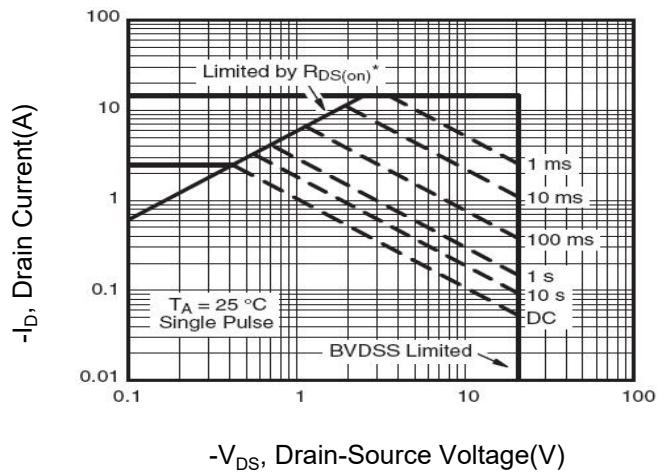
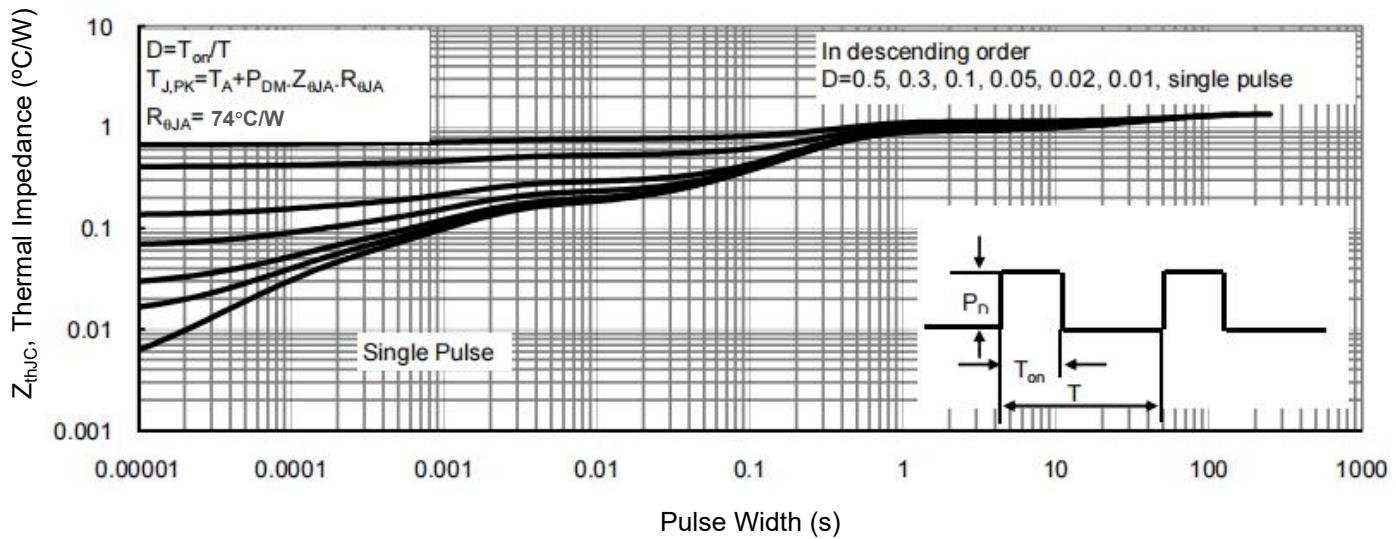
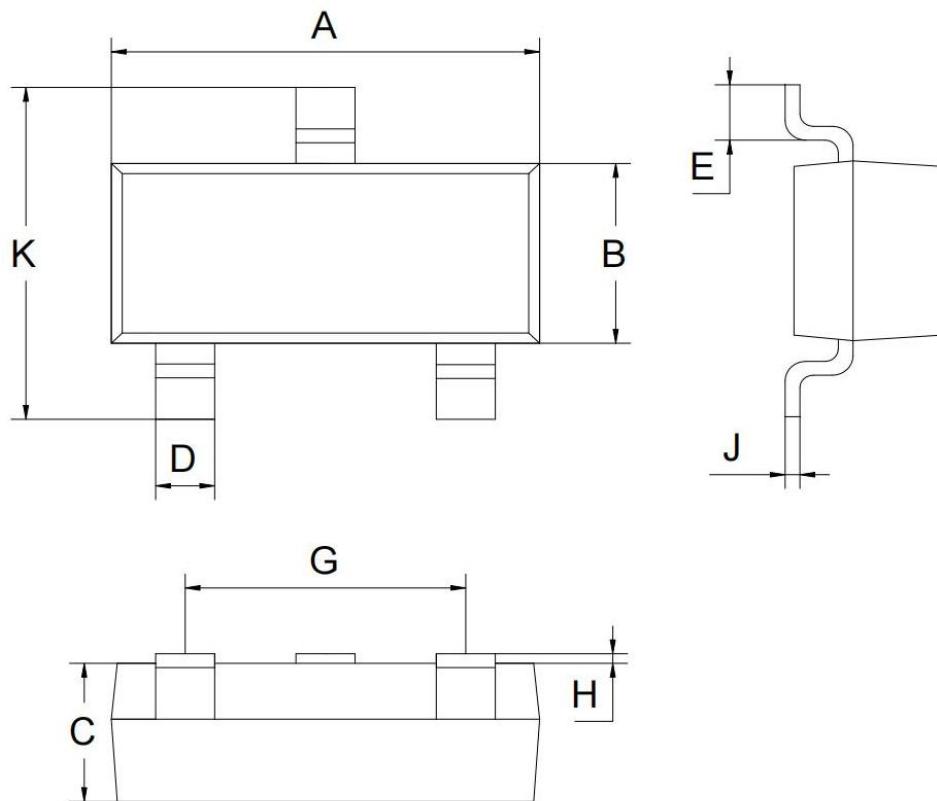


Figure 9. Normalized Maximum Transient Thermal Impedance



SOT-23 Package information



SOT-23			
Dim	MIN	NOM	MAX
A	2.80	2.90	3.00
B	1.20	1.30	1.40
C	0.90	1.00	1.10
D	0.39	0.40	0.45
E	0.20MIN		
G	1.90REF		
H	0.00	-	0.10
J	0.05	0.10	0.15
K	2.30	2.40	2.50
All Dimensions in mm			